

**SURFACE MOUNT RECTIFIERS**

**VOLTAGE RANGE: 50 --- 1000 V**  
**CURRENT: 3.0 A**

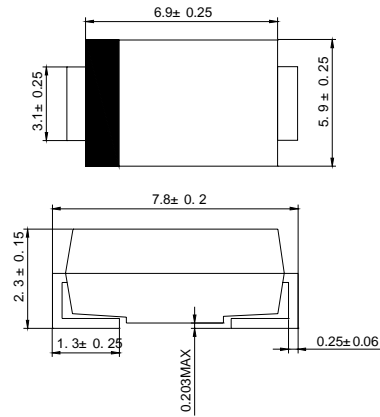
**FEATURES**

- ◇ Low cost
- ◇ Low leakage
- ◇ Low forward voltage drop
- ◇ High current capability
- ◇ Easily cleaned with Alcohol, Isopropanol and similar solvents
- ◇ The plastic material carries U/L recognition 94V-0

**MECHANICAL DATA**

- ◇ Case: JEDEC DO-214AB, molded plastic
- ◇ Terminals: Solderable per MIL- STD-202, Method 208
- ◇ Polarity: Color band denotes cathode
- ◇ Weight: 0.007 ounces, 0.21 grams
- ◇ Mounting position: Any

**DO-214AB(SMC)**



Dimensions in millimeters

**MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS**

Ratings at 25°C ambient temperature unless otherwise specified.

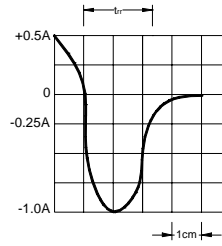
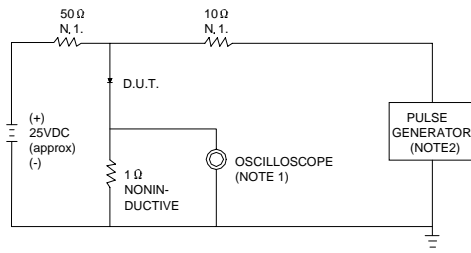
Single phase, half wave, 60 Hz, resistive or inductive load. For capacitive load, derate by 20%.

		UF3A	UF3B	UF3D	UF3G	UF3J	UF3K	UF3M	UNITS
Maximum recurrent peak reverse voltage	$V_{RRM}$	50	100	200	400	600	800	1000	V
Maximum RMS voltage	$V_{RMS}$	35	70	140	280	420	560	700	V
Maximum DC blocking voltage	$V_{DC}$	50	100	200	400	600	800	1000	V
Maximum average forward rectified current @ $T_L=90^\circ C$	$I_{F(AV)}$	3.0							A
Peak forward surge current 8.3ms single half-sine-wave superimposed on rated load @ $T_J=125^\circ C$	$I_{FSM}$	100							A
Maximum instantaneous forward voltage at 3.0 A	$V_F$	1.0		1.4		1.7			V
Maximum reverse current @ $T_A=25^\circ C$ at rated DC blocking voltage @ $T_A=125^\circ C$	$I_R$	10 100							$\mu A$
Typical reverse recovery time (Note1)	$t_{rr}$	50				75			ns
Typical junction capacitance (Note2)	$C_J$	15				12			pF
Typical thermal resistance (Note3)	$R_{\theta JA}$	15							$^\circ C/W$
Operating junction temperature range	$T_J$	- 55 ---- + 150							$^\circ C$
Storage temperature range	$T_{STG}$	- 55 ---- + 150							$^\circ C$

NOTE: 1. Measured with  $I_F=0.5A$ ,  $I_R=1A$ ,  $I_{rr}=0.25A$ .

2. Measured at 1.0MHZ and applied reverse voltage of 4.0V DC.

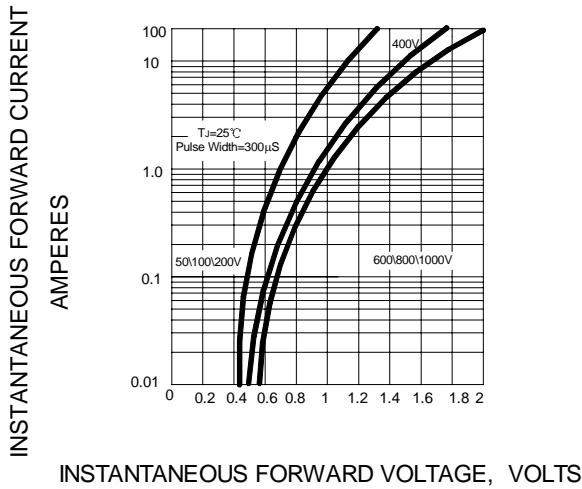
**FIG.1 -- TEST CIRCUIT DIAGRAM AND REVERSE RECOVERY TIME CHARACTERISTIC**



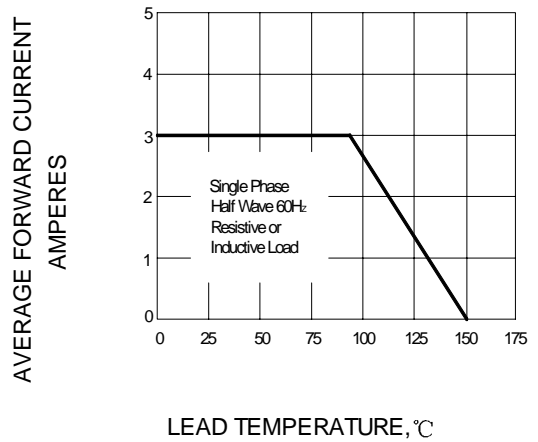
NOTES:1. RISE TIME = 7ns MAX.INPUT IMPEDANCE = 1MΩ .22pF.  
2. RISE TIME =10ns MAX.SOURCE IMPEDANCE=50 Ω.

SET TIME BASE FOR 20/30 ns/cm

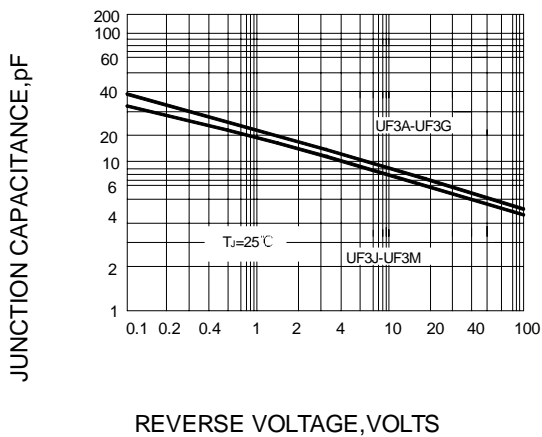
**FIG.2 -- TYPICAL FORWARD CHARACTERISTIC**



**FIG.3 -- FORWARD DERATING CURVE**



**FIG.4 -- TYPICAL JUNCTION CAPACITANCE**



**FIG.5 -- PEAK FORWARD SURGE CURRENT**

